Supplementary Information

Crown-ether functionalized fullerene as solution-processable cathode buffer layer for high performance perovskite and polymer solar cells

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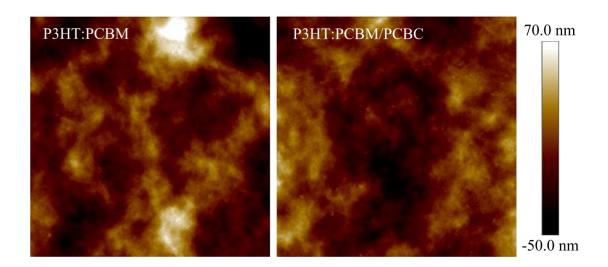


Fig. S1 AFM height images of the pristine P3HT:PC₆₀BM and P3HT:PC₆₀BM/PCBC films prepared on ITO/PEDOT:PSS substrates for a 5 μ m×5 μ m surface area. The root-mean-square (RMS) roughnesses of the P3HT:PC₆₀BM films with and without a PCBC layer on top are 15.9 and 19.9 nm, respectively.

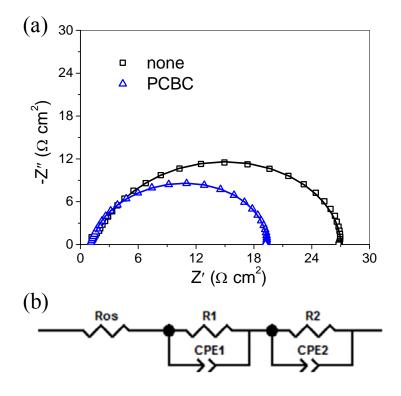


Fig. S2 (a) The Nyquist plots (symbols) and fitted curves (solid curves) for the pero-SCs based on $CH_3NH_3PbI_{3-x}Cl_x$ without and with PCBC CBL, measured in the dark and with applied voltage near the V_{oc} (0.97 V). (b) The equivalent circuit used for fitting the impedance data.

 $\textbf{Table S1} \ \ \text{The fitted ACIS parameters of planar pero-SCs based on } CH_3NH_3PbI_{3-x}Cl_x.$

CBL	$R_{\rm os}$ $(\Omega \ {\rm cm}^2)$	R_1 $(\Omega \text{ cm}^2)$	CPE ₁ -T (μF cm ⁻²)	CPE ₁ -P	R_2 $(\Omega \text{ cm}^2)$	CPE ₂ -T (μF cm ⁻²)	CPE ₂ -P
None	1.42	3.49	2.48	0.83	22.14	0.18	0.98
PCBC	1.32	4.04	0.52	0.94	13.96	0.14	1.03